



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

**SURFACE MOUNT
PNP Digital Silicon Transistor**

VOLTAGE 50 Volts CURRENT 30 mAmpere

CHDTA144VKPT

APPLICATION

- * Switching circuit, Inverter, Interface circuit, Driver circuit.

FEATURE

- * Small surface mounting type. (SC-59/SOT346)
- * High current gain.
- * Suitable for high packing density.
- * Low collector-emitter saturation.
- * High saturation current capability.
- * Internal isolated PNP transistors in one package.
- * Built in bias resistor($R_1=47\text{k}\Omega$, Typ.)

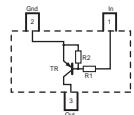
CONSTRUCTION

- * One PNP transistors and bias of thin-film resistors in one package.

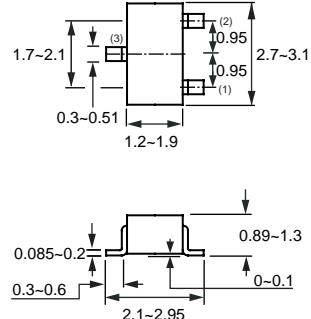
MARKING

VK1

CIRCUIT



SC-59/SOT-346



Dimensions in millimeters

SC-59/SOT-346

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	Supply voltage		-	-50	V
V _{IN}	Input voltage		-40	+15	V
I _O	DC Output current		-	-30	mA
I _{C(MAX.)}			-	-100	
P _{TOT}	Total power dissipation	T _{amb} ≤ 25 °C, Note 1	-	200	mW
T _{STG}	Storage temperature		-55	+150	°C
T _J	Junction temperature		-	150	°C
R _{θJ-S}	Thermal resistance	junction - soldering point	-	140	°C/W

Note

- Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC (CHDTA144VKPT)

CHARACTERISTICS

$T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{I(off)}$	Input off voltage	$I_o=-100\mu\text{A}; V_{cc}=-5.0\text{V}$	-1.0	-	-	V
$V_{I(on)}$	Input on voltage	$I_o=-2\text{mA}; V_o=-0.3\text{V}$	-	-	-6.0	V
$V_{O(on)}$	Output voltage	$I_o=-10\text{mA}; I_i=-0.5\text{mA}$	-	-0.1	-0.3	V
I_i	Input current	$V_i=-5\text{V}$	-	-	-0.16	mA
$I_{C(off)}$	Output current	$V_i=0\text{V}; V_{cc}=-50\text{V}$	-	-	-0.5	μA
h_{FE}	DC current gain	$I_o=-5\text{mA}; V_o=-5.0\text{V}$	33	-	-	
R_1	Input resistor		32.9	47	61.1	$\text{k}\Omega$
R_2/R_1	Resistor ratio		0.17	0.21	0.26	
f_T	Transition frequency	$I_E=5\text{mA}, V_{CE}=-10.0\text{V}$ $f=100\text{MHz}$	-	250	-	MHz

Note

1. Pulse test: $t_p \leq 300\mu\text{s}; \delta \leq 0.02$.